

Features

- AEC-Q101 Qualified
- · Split Gate Trench MOSFET Technology
- Low R_{DS(on)} & FOM
- · Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- EpoxyMeets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

P-CHANNEL MOSFET

Maximum Ratings

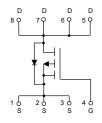
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance:60°C/W Junction to Ambient(Steady-State)(Note2)
- Thermal Resistance:1.7°C/W Junction to Case(Steady-State)

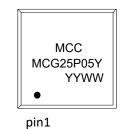
				,
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	-48	V
Gate-Source Volltage		V _{GS}	±20	V
Continuous Drain Current	T _C =25°C	- I _D	-25	^
	T _C =100°C		-16	A
Pulsed Drain Current ^(Note3)		I _{DM}	-100	Α
Total Power Dissipation ^(Note4)		P _D	74	W
Single Pulsed Avalanche Energy ^(Note5)		E _{AS}	81	mJ

Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_{D} is based on max. junction temperature, using junction-case thermal resistance.
- 5. V_{GS} =-10V, V_{DD} =-50V, R_{G} =25 Ω ,L=0.5mH.

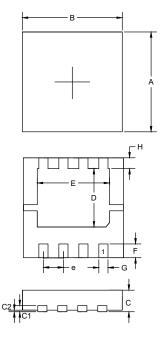
Internal Structure and Marking Code





4 codes in total YY is the year WW is the week

DFN3333



DIMENSIONS					
DIM I	INC	INCHES		M	NOTE
	MIN	MAX	MIN	MAX	NOIL
Α	0.126	0.130	3.20	3.30	
В	0.126	0.130	3.20	3.30	
С	0.030	0.033	0.75	0.85	
C1	0.007	0.009	0.18	0.22	
C2		0.002		0.05	
D	0.071	0.079	1.80	2.00	
Е	0.087	0.098	2.20	2.50	
F	0.016	0.020	0.40	0.50	
G	0.010	0.014	0.25	0.35	
Н	0.012	0.016	0.30	0.40	
е	0.024	0.028	0.60	0.70	

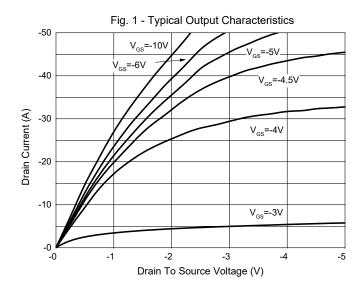


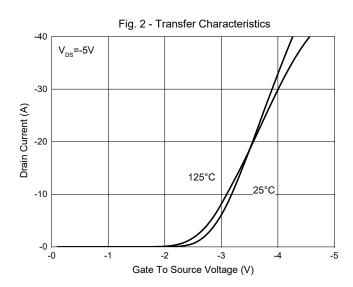
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

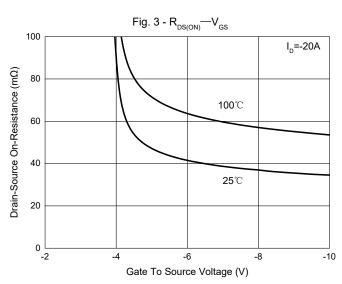
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics					I		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-48			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-48V, V _{GS} =0V			-1	μΑ	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.5	-2.1	-2.7	V	
Drain-Source On-Resistance	В	V _{GS} =-10V, I _D =-20A	35 45		45	mΩ	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-10A		47	61	11122	
Gate Resistance	R _g	F=1 MHz, Open drain		12		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				-25	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-20A			-1.3	V	
Reverse Recovery Time	t _{rr}	1 - 204 41 /44-4004/115		28.3		ns	
Reverse Recovery Charge	Q _{rr}	I _F =-20A, dI _F /dt=100A/μs		20.2		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			1024			
Output Capacitance	C _{oss}	V _{DS} =-30V,V _{GS} =0V,f=1MHz		386		pF	
Reverse Transfer Capacitance	C _{rss}			22			
Total Gate Charge	Q_g			17.4			
Gate-Source Charge	Q _{gs}	V _{DS} =-30V,V _{GS} =-10V,I _D =-20A		3.8		nC	
Gate-Drain Charge	Q_{gd}			3.0			
Turn-On Delay Time	t _{d(on)}			7.9			
Turn-On Rise Time	t _r	V _{DD} =-30V, V _{GS} =-10V ,		4.6			
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =6 Ω		42.4		ns	
Turn-Off Fall Time	t _f			15.7			

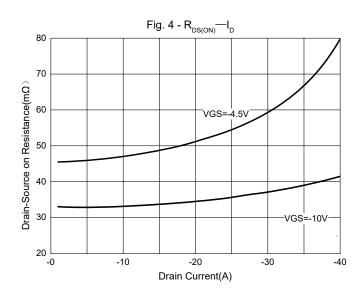


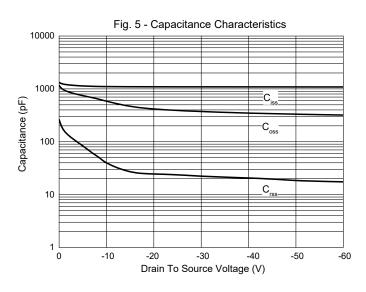
Curve Characteristics

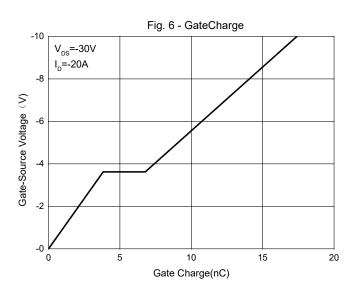






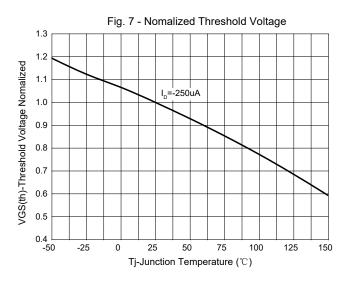


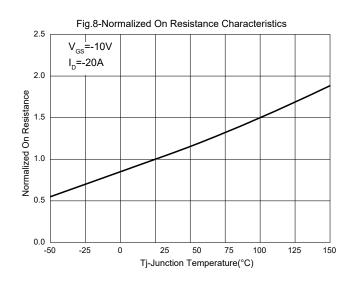


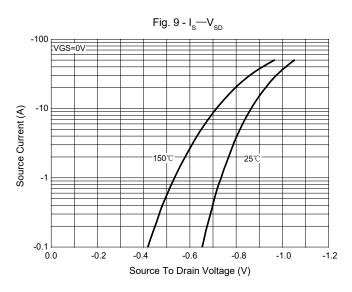


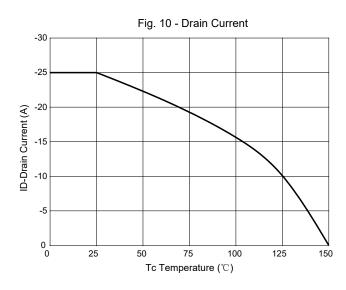


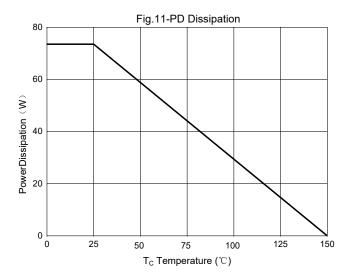
Curve Characteristics





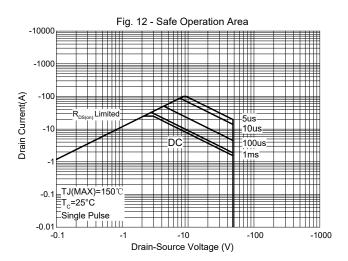


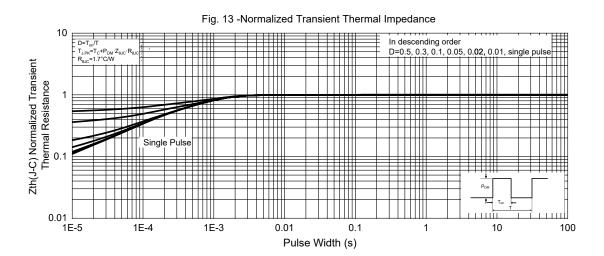






Curve Characteristics





Rev.4-1-07202023 5/6 MCCSEMI.COM



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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